

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT240P,TC74ACT240F,TC74ACT240FW,TC74ACT240FT TC74ACT244P,TC74ACT244F,TC74ACT244FW,TC74ACT244FT

Octal Bus Buffer

TC74ACT240P/F/FW/FT Inverted, 3-State Outputs

TC74ACT244P/F/FW/FT Non-Inverted, 3-State Outputs

Note: xxxFW (JEDEC SOP) is not available in Japan.

The TC74ACT240 and 244 are advanced high speed CMOS OCTAL BUS BUFFERS fabricated with silicon gate and double-layer metal wiring C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74ACT240 is an inverting 3-state buffer while the 74ACT244 is non-inverting. Both devices have two active-low output enables.

These devices are designed to be used in such applications as 3-state memory address drivers.

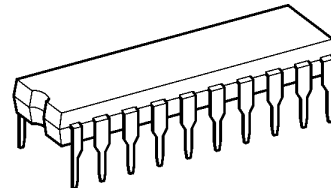
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 5.0 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 8 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V}$ (max)
 $V_{IH} = 2.0 \text{ V}$ (min)
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24 \text{ mA}$ (min)
Capability of driving 50Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Pin and function compatible with 74F240/244

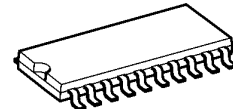
Weight	
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

TC74ACT240P, TC74ACT244P

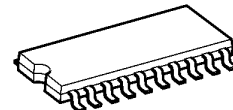


DIP20-P-300-2.54A

TC74ACT240F, TC74ACT244F

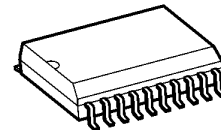


SOP20-P-300-1.27A



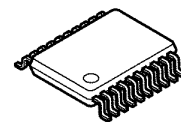
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TC74ACT240FW, TC74ACT244FW



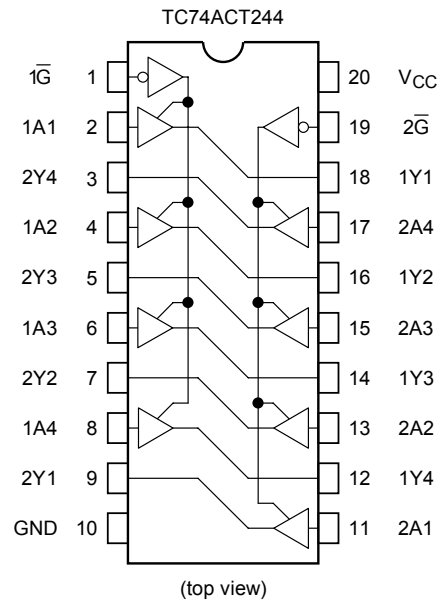
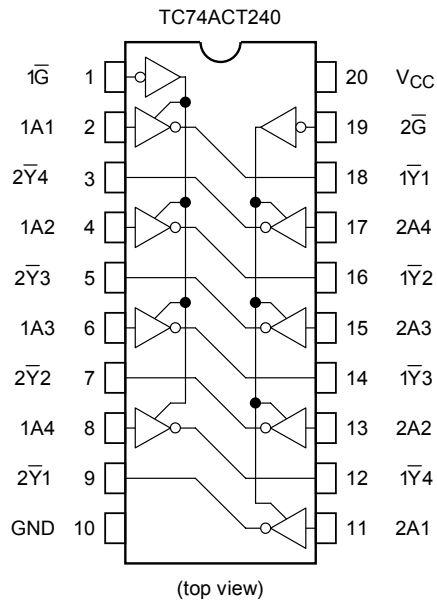
SOL20-P-300-1.27

TC74ACT240FT, TC74ACT244FT

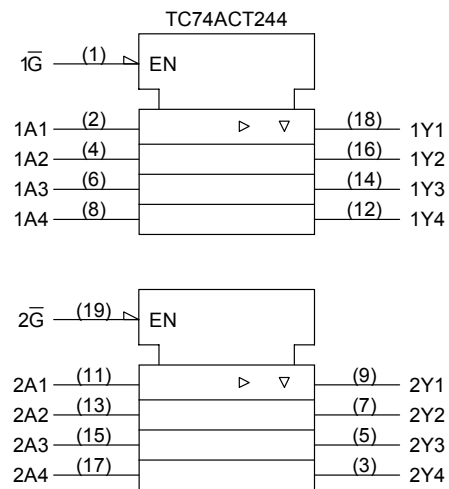
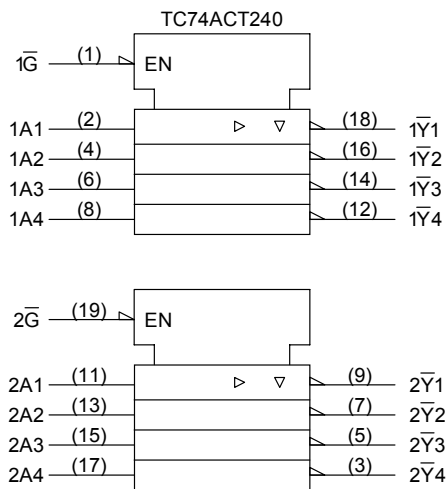


TSSOP20-P-0044-0.65A

Pin Assignment



IEC Logic Symbol



Truth Table

Inputs		Outputs	
$\bar{G}$	A_n	Y_n (244)	$\bar{Y}_n$ (240)
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 50	mA
DC output current	I_{OUT}	± 50	mA
DC V_{CC} /ground current	I_{CC}	± 200	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of $T_a = -40$ to 65°C . From $T_a = 65$ to 85°C a derating factor of -10 mW/ $^\circ\text{C}$ should be applied up to 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	4.5 to 5.5	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 10	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics
DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V _{IH}	—		4.5 to 5.5	2.0	—	—	2.0	—	V
Low-level input voltage	V _{IL}	—		4.5 to 5.5	—	—	0.8	—	0.8	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 µA	4.5	4.4	4.5	—	4.4	—	V
			I _{OH} = -24 mA	4.5	3.94	—	—	3.80	—	
			I _{OH} = -75 mA (Note)	5.5	—	—	—	3.85	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 µA	4.5	—	0.0	0.1	—	0.1	V
			I _{OL} = 24 mA	4.5	—	—	0.36	—	0.44	
			I _{OL} = 75 mA (Note)	5.5	—	—	—	—	1.65	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	—	—	±0.5	—	±5.0	µA
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	—	—	±0.1	—	±1.0	µA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	8.0	—	80.0	µA
	I _C	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	—	—	1.35	—	1.5	mA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

AC Characteristics (C_L = 50 pF, R_L = 500 Ω, input: t_r = t_f = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	Min	Typ.	Max	Min	Max	
Propagation delay time	t _{pLH} t _{pHL}	—	5.0 ± 0.5	—	5.7	8.0	1.0	9.0	ns
Output enable time	t _{pZL} t _{pZH}	—	5.0 ± 0.5	—	6.0	9.0	1.0	10.5	ns
Output disable time	t _{pLZ} t _{pHZ}	—	5.0 ± 0.5	—	5.9	8.5	1.0	10.0	ns
Input capacitance	C _{IN}	—		—	5	10	—	10	pF
Output capacitance	C _{OUT}	—		—	10	—	—	—	pF
Power dissipation capacitance	C _{PD} (Note)	TC74ACT240		—	25	—	—	—	pF
		TC74ACT244		—	29	—	—	—	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

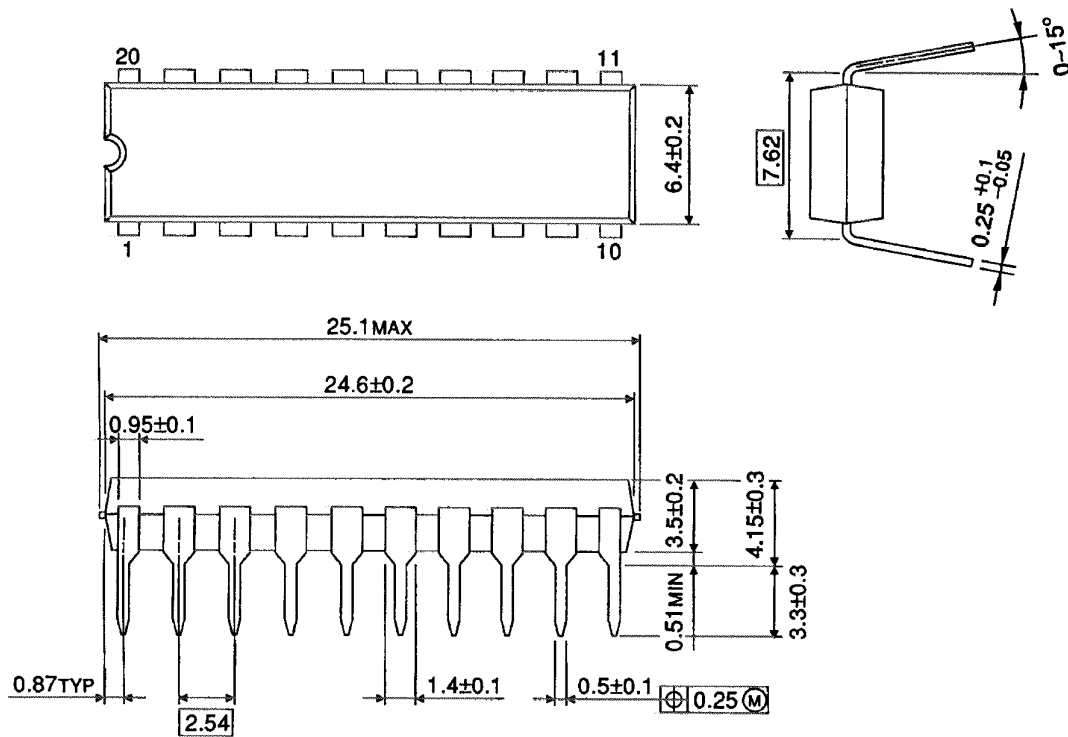
Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

Package Dimensions

DIP20-P-300-2.54A

Unit : mm

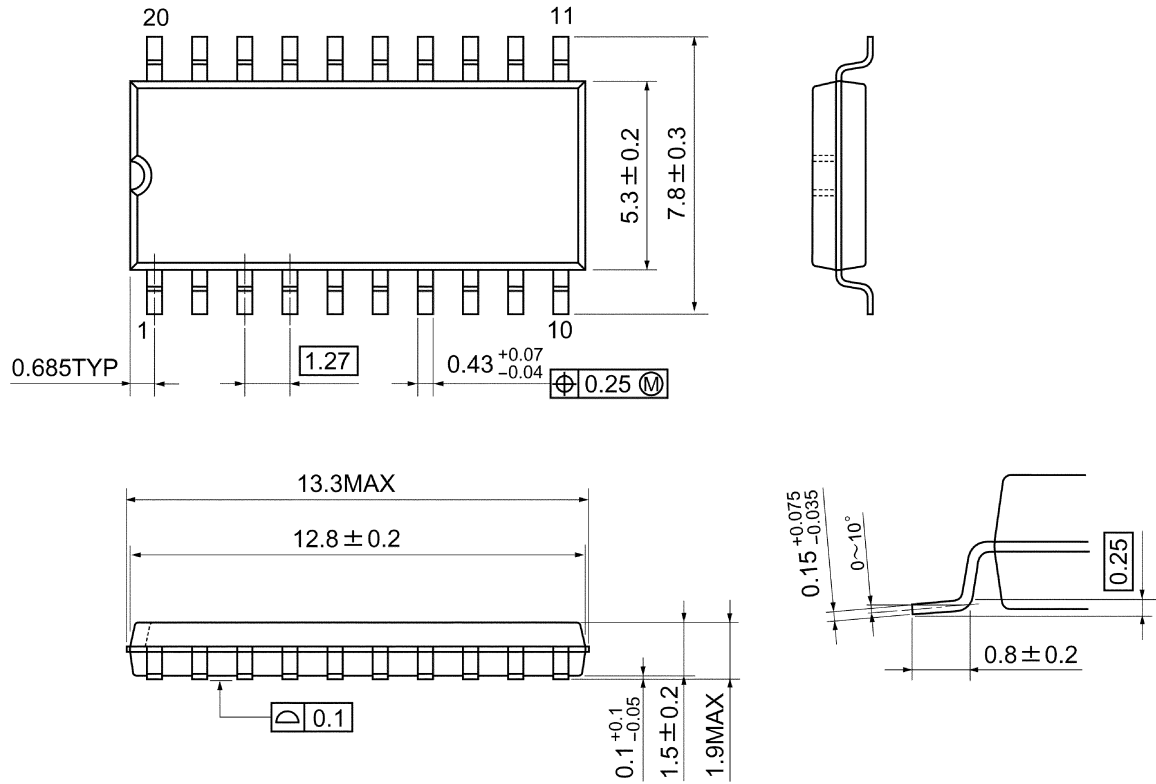


Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A

Unit: mm

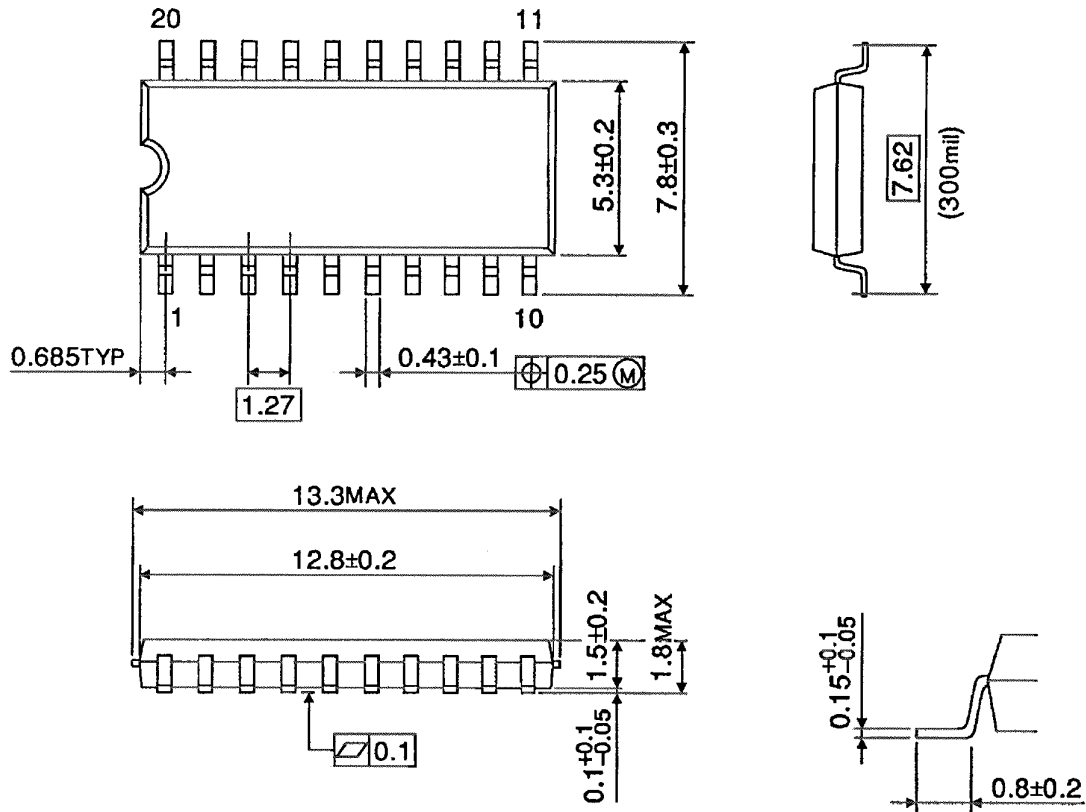


Weight: 0.22 g (typ.)

Package Dimensions

SOP20-P-300-1.27

Unit : mm

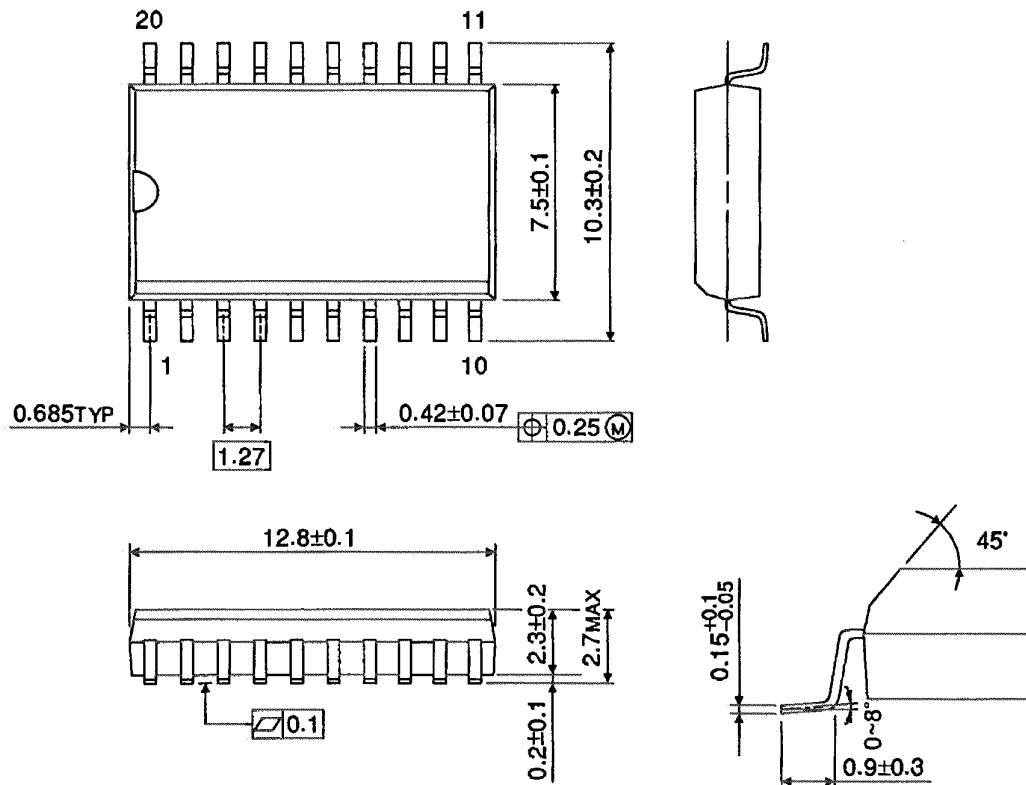


Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



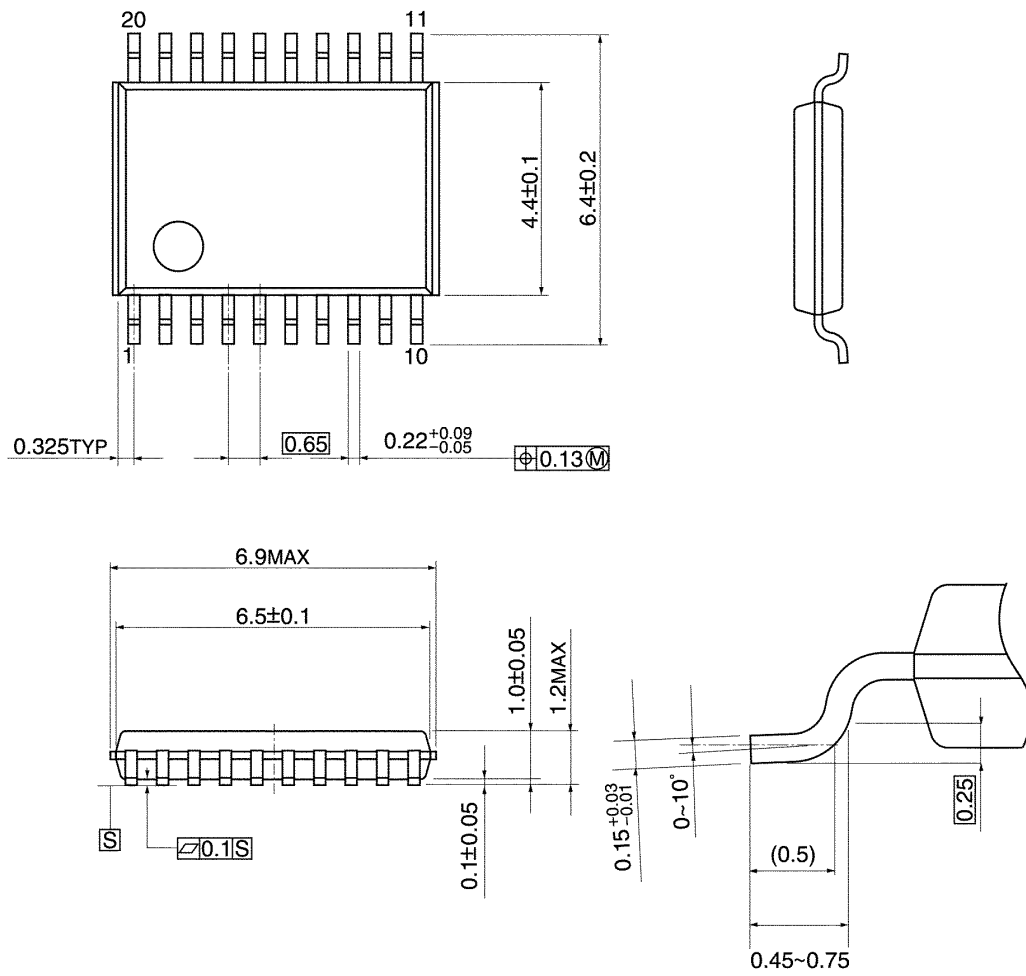
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



Weight: 0.08 g (typ.)

Note: Lead (Pb)-Free Packages

DIP20-P-300-2.54A SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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